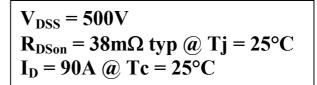
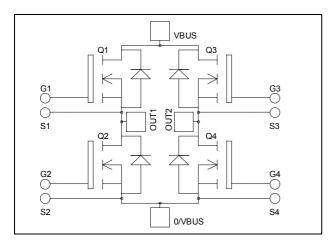


Full - Bridge MOSFET Power Module





Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

G1 VSUS	O/VBUS OUT1
53	52 53 54 54 64
	OUI2

Absolute maximum ratings

Symbol Parameter Max ratings Unit Drain - Source Breakdown Voltage 500 V V_{DSS} $T_c = 25$ °C 90 I_D Continuous Drain Current $T_c = 80$ °C 67 Α Pulsed Drain current 360 $I_{DM} \\$ V_{GS} V Gate - Source Voltage ± 30 Drain - Source ON Resistance 45 R_{DSon} $m\Omega$ P_{D} **Maximum Power Dissipation** $T_c = 25$ °C 694 W Avalanche current (repetitive and non repetitive) 46 I_{AR} A E_{AR} Repetitive Avalanche Energy 50 mJ Single Pulse Avalanche Energy 2500 E_{AS}

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 500V$ $T_j = 25^{\circ}C$			200	μA
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 400V$ $T_j = 125^{\circ}C$			1000	μΑ
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 45A$		38	45	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		11.2		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		2.4		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.18		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		246		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 250V$		66		nC
Q_{gd}	Gate – Drain Charge	$I_D = 90A$		130		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		18		
T_{r}	Rise Time	$\begin{aligned} V_{GS} &= 15V \\ V_{Bus} &= 333V \\ I_D &= 90A \\ R_G &= 2\Omega \end{aligned}$		35		ns
$T_{d(off)}$	Turn-off Delay Time			87		
T_{f}	Fall Time			77		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1510		1
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 90A, R_G = 2\Omega$		1452		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2482		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 90A, R_G = 2\Omega$		1692		μJ

Source - Drain diode ratings and characteristics

~ 0 422 0 0	21411 41040 144116 4141 4141 4141							
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_S	Continuous Source current		$Tc = 25^{\circ}C$			90	Α	
	(Body diode)		$Tc = 80^{\circ}C$			67	A	
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -90A$				1.3	V	
dv/dt	Peak Diode Recovery •					15	V/ns	
+	Payarsa Pagayary Tima		$T_j = 25$ °C		233		ne	
t_{rr}	t _{rr} Reverse Recovery Time	$I_S = -90A$ $V_R = 333V$	$T_j = 125$ °C		499		ns	
Q_{rr}	Q _{rr} Rever	Reverse Recovery Charge	$di_s/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		3.8		μC
		Reverse Recovery Charge		$T_{i} = 125^{\circ}C$		11.4		μΟ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

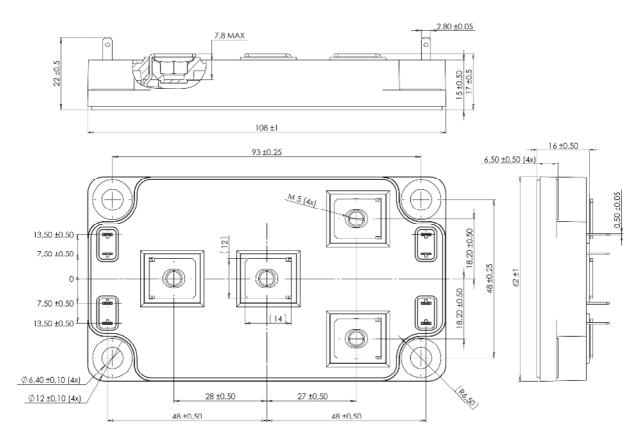
 $I_S \leq \text{--} 90 A \qquad \text{di/dt} \leq 700 A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.18	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

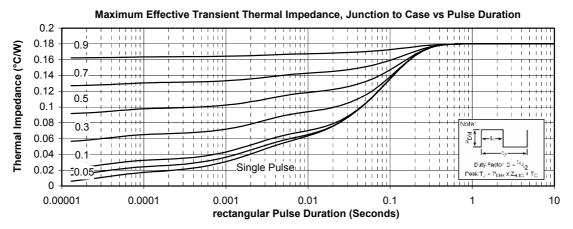
SP6 Package outline (dimensions in mm)



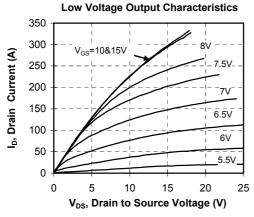
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

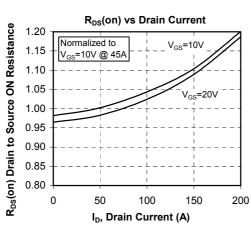


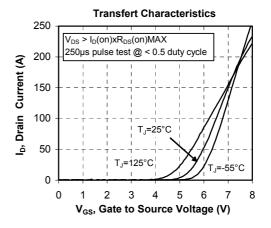
Typical Performance Curve

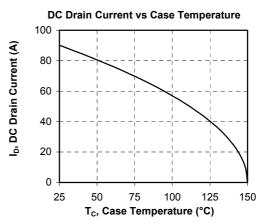


www.microsemi.com

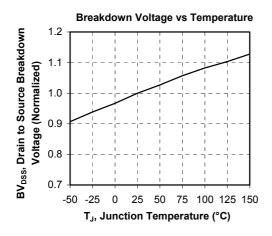


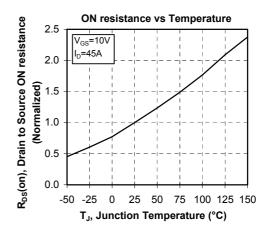


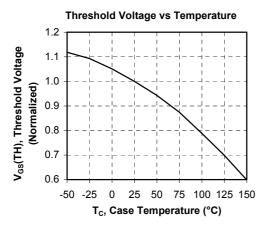


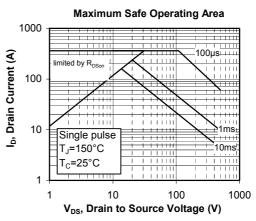


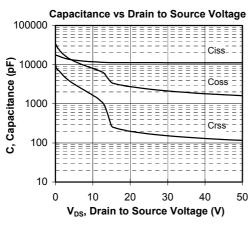


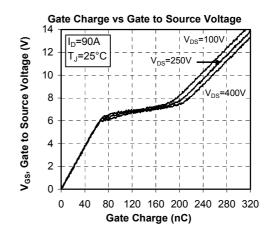




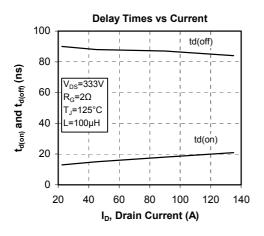


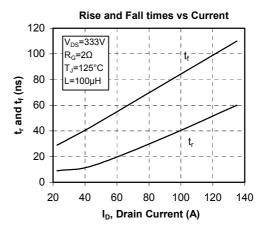


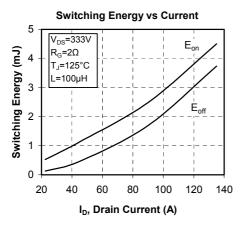


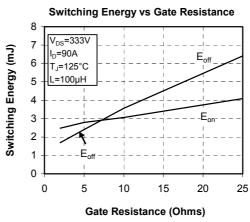


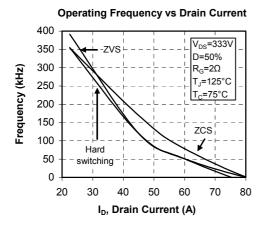


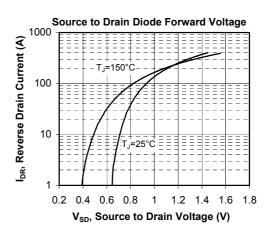














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